NSN 5961-01-095-1213

Transistor - Page 1 of 1

AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-095-1213

Inclosure Material:

Metal

Overall Length:

1.266 inches

Overall Height:

Between 0.250 inches and 0.340 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact-darlington connected

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case and burn in

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc

Current Rating Per Characteristic:

8.00 milliamperes source cutoff current and 50.00 milliamperes source cutoff current

Power Rating Per Characteristic:

75.0 watts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0